

# **Cypress Semiconductor Package Qualification Report**

**QTP# 044006 VERSION 1.0  
November 2006**

**144-Ball Fine Pitch Ball Grid Array (FBGA)  
(13 x 13 x 1.6mm)  
Stacked Die  
MSL3, 220C Solder Reflow  
ASE-Taiwan**

## **CYPRESS TECHNICAL CONTACT FOR QUALIFICATION DATA:**

Rene Rodgers  
Principal Reliability Engineer  
(408) 943-2732

Mira Ben-Tzur  
Quality Engineering Director  
(408) 943-2675

### PACKAGE QUALIFICATION HISTORY

<b>Qual Report</b>	<b>Description of Qualification Purpose</b>	<b>Date Comp</b>
044006	144-Ball FBGA (13 x 13 x 1.6mm), Stacked Die, MSL3, 220C Reflow assembled at ASE-Taiwan	Mar 05

MAJOR PACKAGE INFORMATION USED IN THIS QUALIFICATION	
<b>Package Designation:</b>	BB144
<b>Package Outline, Type, or Name:</b>	144-Ball Fine Pitch Ball Grid Array (FBGA)
<b>Mold Compound Name/Manufacturer:</b>	KE-G2270
<b>Mold Compound Flammability Rating:</b>	V-O per UL94
<b>Oxygen Rating Index:</b>	N/A
<b>Substrate Material:</b>	BT
<b>Ball Composition / Diameter:</b>	SnPb 63/37, 0.45mm
<b>Die Backside Preparation Method/Metallization:</b>	Backgrind to 6 mils
<b>Die Separation Method:</b>	Saw Singulate
<b>Die Attach Supplier:</b>	Ablestik and QMI
<b>Die Attach Material:</b>	2025D (Die Attach 1 and 3) and QMI536 (Die Attach 2)
<b>Die Attach Method:</b>	Epoxy
<b>Bond Diagram Designation:</b>	10-06132
<b>Wire Bond Method:</b>	Thermosonic
<b>Wire Material/Size:</b>	Au, 1.0 mil
<b>Thermal Resistance Theta JA °C/W:</b>	18 °C/W
<b>Package Cross Section Yes/No:</b>	N/A
<b>Assembly Process Flow:</b>	49-41024
<b>Name/Location of Assembly (prime) facility:</b>	ASE-Taiwan
<b>MSL Level</b>	3
<b>Reflow Profile</b>	220C

ELECTRICAL TEST / FINISH DESCRIPTION	
<b>Test Location:</b>	CML-K, USA-SJC

**RELIABILITY TESTS PERFORMED PER SPECIFICATION REQUIREMENTS**

<b>Stress/Test</b>	<b>Test Condition (Temp/Bias)</b>	<b>Result P/F</b>
Acoustic Microscopy Test	Cypress Spec. 25-00104	P
Ball Shear	Cypress Spec. 24-00018	P
Bond Pull	Cypress Spec. 24-00002	P
Die Shear	Cypress Spec. 12-00215	P
Electrostatic Discharge Charge Device Model (ESD-CDM)	500V Cypress Spec. 25-00020	P
Electrostatic Discharge Human Body Model (ESD-HBM)	2,200V JESD22, Method A114-B	P
Electrostatic Discharge Human Body Model (ESD-HBM)	2,200V MIL-STD-883, Method 3015.7	P
External Visual	Cypress Spec 25-00038	P
Internal Visual	Cypress Spec 25-00017	P
High Accelerated Saturation	130°C, 3.3V, 85%RH Precondition: JESD22 Moisture Sensitivity MSL3 192 Hrs., 30°C/60%RH+3IR-Reflow, 220°C+0, -5°C	P
High Temperature Storage	150C, no bias	P
Physical Dimension	Cypress Spec. 25-00031	P
Pressure Cooker	121C, 100%RH, 15 Psig Precondition: JESD22 Moisture Sensitivity MSL3 192 Hrs., 30°C/60%RH+3IR-Reflow, 220°C+0, -5°C	P
Temperature Cycle	JEDEC22, Condition C, -65°C to 150°C Precondition: JESD22 Moisture Sensitivity MSL3 192 Hrs., 30°C/60%RH+3IR-Reflow, 220°C+0, -5°C	P
Thermal Shock	Cypress Spec. 25-00014	P
X-Ray	Cypress Spec 12-00292	P

## Reliability Test Data

QTP #: 044006

<i>Device</i>	<i>Fab Lot #</i>	<i>Assy Lot #</i>	<i>Assy Loc</i>	<i>Duration</i>	<i>Samp</i>	<i>Rej</i>	<i>Failure Mechanism</i>
<b>STRESS: ACOUSTIC, MSL3</b>							
CY7C0833AV (7C08333A)	4429608	610452519	TAIWAN-G	COMP	15	0	
<b>STRESS: BOND PULL</b>							
CY7C0832AV (7C08333A)	4429608	610452044	TAIWAN-G	COMP	10	0	
<b>STRESS: BALL SHEAR</b>							
CY7C0832AV (7C08333A)	4429608	610452044	TAIWAN-G	COMP	10	0	
<b>STRESS: DIE SHEAR</b>							
CY7C0832AV (7C08333A)	4429608	610452044	TAIWAN-G	COMP	15	0	
<b>STRESS: ESD-CHARGE DEVICE MODEL, 500V</b>							
CY7C0833AV (7C08333A)	4429608	610452519	TAIWAN-G	COMP	9	0	
<b>STRESS: ESD-HUMAN BODY CIRCUIT PER JESD22, METHOD A114-B, 2,200V</b>							
CY7C0833AV (7C08333A)	4429608	610452519	TAIWAN-G	COMP	9	0	
<b>STRESS: ESD-HUMAN BODY CIRCUIT PER MIL STD 883, METHOD 3015, 2,200V</b>							
CY7C0833AV (7C08333A)	4429608	610452519	TAIWAN-G	COMP	3	0	
<b>STRESS: EXTERNAL VISUAL</b>							
CY7C0832AV (7C08333A)	4429608	610452044	TAIWAN-G	COMP	15	0	
<b>STRESS: INTERNAL VISUAL</b>							
CY7C0832AV (7C08333A)	4429608	610452044	TAIWAN-G	COMP	5	0	
<b>STRESS: PHYSICAL DIMENSIONS</b>							
CY7C0832AV (7C08333A)	4429608	610452044	TAIWAN-G	COMP	5	0	
<b>STRESS: X-RAY</b>							
CY7C0832AV (7C08333A)	4429608	610452044	TAIWAN-G	COMP	15	0	
<b>STRESS: HI-ACCEL SATURATION TEST (130C, 85%RH, 3.3V), PRE COND 192 HR 30C/60%RH, MSL3</b>							
CY7C0833AV (7C08333A)	4429608	610452519	TAIWAN-G	128	50	0	
<b>STRESS: HIGH TEMPERATURE STORAGE, PLASTIC, 150C</b>							
CY7C0833AV (7C08333A)	4429608	610452519	TAIWAN-G	500	46	0	
CY7C0833AV (7C08333A)	4429608	610452519	TAIWAN-G	1000	46	0	

## Reliability Test Data

QTP #: 044006

<i>Device</i>	<i>Fab Lot #</i>	<i>Assy Lot #</i>	<i>Assy Loc</i>	<i>Duration</i>	<i>Samp</i>	<i>Rej</i>	<i>Failure Mechanism</i>
<b>STRESS: PRESSURE COOKER TEST (121C, 100%RH), 15 Psig, PRE COND 192 HR 30C/60%RH, MSL3</b>							
CY7C0833AV (7C08333A)	4429608	610452519	TAIWAN-G	168	48	0	
<b>STRESS: TC COND. C -65C TO 150C, PRE COND 192 HRS 30C/60%RH, MSL3</b>							
CY7C0833AV (7C08333A)	4429608	610452519	TAIWAN-G	300	48	0	
CY7C0833AV (7C08333A)	4429608	610452519	TAIWAN-G	500	48	0	
CY7C0833AV (7C08333A)	4429608	610452519	TAIWAN-G	1000	48	0	
CY7C0832AV (7C08323A)	4429608	610452044	TAIWAN-G	300	50	0	
CY7C0832AV (7C08323A)	4429608	610452044	TAIWAN-G	500	50	0	
CY7C0832AV (7C08323A)	4429608	610452044	TAIWAN-G	1000	50	0	
CY7C0832AV (7C08323A)	4429608	610454901	TAIWAN-G	300	50	0	
CY7C0832AV (7C08323A)	4429608	610454901	TAIWAN-G	500	49	0	
CY7C0832AV (7C08323A)	4429608	610454901	TAIWAN-G	1000	49	0	
<b>STRESS: THERMAL SHOCK</b>							
CY7C0832AV (7C08323A)	4429608	610452044	TAIWAN-G	100	50	0	
CY7C0832AV (7C08323A)	4429608	610452044	TAIWAN-G	200	50	0	